RADIATION OF ULTRA-WIDEBAND ELECTROMAGNETIC PULSES
BY PULSED EXCITATION OF RECTANGULAR ANTENNA *

S. Ašmontas a, F. Anisimovas a, L. Dapkus a, J. Gradauskas a, O. Kiprijanovič a, I. Prosyčėvas b, J. Puišo c, K. Šlapikas b, and B. Vengalis a

a Semiconductor Physics Institute, A. Goštauto 11, LT-01108 Vilnius, Lithuania
E-mail: kipriot@pfi.lt
b Institute of Physical Electronics, Kaunas University of Technology, Savanorių 271, LT-50131 Kaunas, Lithuania
c Department of Physics, Kaunas University of Technology, Studentų 50, LT-51368 Kaunas, Lithuania

Received 3 October 2008; revised 2 February 2009; accepted 19 March 2009

Rectangular (2.5×2 cm²) antennas fastened to an end of a transmission line were pulse-excited by 0.5 ns rise time pulses for radiation of ultra-wideband signals. Wideband horn antennas were used for receiving the signals and wideband sampling oscilloscope was used for their visualization. The signals were registered in 1–5.6 GHz frequency range and had the quasi-Gauss envelope form. The plane antennas made of Cu, resistive Al, and resistive nanostructured Ni thin films on supporting polyethylene terephthalate of 100 μm thickness were used. It is shown that the radiation induced by pulsed excitation can be used to control parameters of resistive coatings, including nanostructured ones, during a deposition process. The metallic nanostructured thin films could be used to create plane radiating and receiving antennas having resistive elements and adapted for ultra-wideband signals. Ultra-wideband antennas with resistive nanostructured coatings, which have properties that can be changed by external electric or magnetic fields or by optical radiation, can be used for modulation of radiated pulses. Further experimental studies are proposed to elaborate metallic nanostructured thin films suitable to withstand possible damages induced by short high power electrical pulses.

Keywords: pulsed excitation, ultra-wideband signals, nanostructured thin films, plane resistive antennas

PACS: 41.20.Jb, 81.15.Jj, 81.70.Ex

1. Introduction

Pulsed electromagnetic radiation is used for practical applications in some of fields, among them are mining prospect, radiolocation [1], and medicine [2]. Nowadays interest in application of electromagnetic ultra-wideband (UWB) signals of picosecond and nanosecond duration is noticeably increasing. This trend is stimulated by rapid development of power electronics and by bandwidth broadening of sampling and real time digital oscilloscopes. Only during the last few years the studies and classification of UWB signals are becoming systematic [3].

In this work we use the following general expression for the UWB signal index η representing a relative frequency band:

\[ \eta = \frac{f_{up} - f_{low}}{f_{up} + f_{low}}, \]  

(1)

where \( f_{up} \) and \( f_{low} \) are the highest and the lowest frequencies of the signal spectrum, respectively. The signals with \( \eta < 0.01 \) belong to a narrow band, the condition \( 0.01 \leq \eta < 0.25 \) corresponds to a wide band, and the signals with \( 0.25 \leq \eta \leq 1 \) belong to UWB signals.

Usually, UWB signals are wave packets having a quasi-Gauss form envelope. In order to evaluate energetic parameters of the radiated pulses having such a form, an approximation of a Gauss form envelope function can be used:

\[ s(t) = A \exp \left( -\frac{\pi t^2}{\tau_p} \right) \exp(i2\pi f_0 t), \quad \tau_p = \frac{k}{f_0}, \]  

(2)

where \( A \) is the amplitude of pulse envelope, \( f_0 \) is the mean frequency, \( \tau_p \) is the effective pulse duration, \( k \)
is an appropriate coefficient. The pulse duration $\tau_p$ is defined at the level of $A \exp(-\pi/4) \approx 0.46 A$.

A single pulse energy, in general, can be defined as

$$E = \alpha P_p \tau_p,$$

where $P_p = A^2/2$ is power at the pulse maximum, and envelope coefficient $\alpha$ depends on pulse form and defined level of pulse duration. For the Gauss envelope $\alpha$ is equal to $1/\sqrt{2} \approx 0.707$ with $\tau_p$ defined at the level of $0.46 A$.

The amplitude spectrum of such a signal is

$$F(f) = A\tau_p \exp \left[ -\pi(f - f_0)^2\tau_p^2 \right].$$

One of the methods to generate UWB signals is excitation of radiating structures by current pulses [4]. Theoretical investigation of UWB signals radiated by plane antennas revealed strong dependence of the signal amplitude on geometrical parameters of the antenna and on direction of radiation [5]. Antennas with resistive elements are used for undistorted receiving of UWB signals and to shorten the duration of the UWB signals. Such antennas can radiate other UWB signals such as Gauss monocycle pulses or bipolar video pulses [3]. Today the creation of plane compact UWB antennas with resistive elements remains an important problem. These antennas could be adapted for high power applications [6, 7].

In this work fast rising electrical pulses were used to generate electromagnetic pulses. Electrical pulses excited rectangular antennas, including those with a resistive coating, which were fastened to the end of transmission line. Wideband pyramidal horns and sampling oscilloscope were used to visualize received signals in the frequency range from 1 to 5.6 GHz. Properties of the generated pulses and influence of resistive coating on their amplitude and form have been investigated.

2. Radiating rectangular antennas

Antennas of rectangular shape ($a = 2.5$ cm, $b = 2$ cm, see Fig. 1) were used in the experiment. The first type of antenna was made of Cu foil of 200 $\mu$m thickness. The second group consisted of two types of antennas made of crumpled and glassy Al foil of about 5 $\mu$m thickness with paper support (total thickness 25 $\mu$m, resistance of square area 0.2 $\Omega$).

The third group of metallic antennas were made of nanostructured Ni thin films prepared on a polyethylene terephthalate (PET, thickness 100 $\mu$m). During preparation PET support was cleaned by oxygen plasma processing ($RF = 13.56$ MHz, $P = 0.3$ W/cm², $t = 5–60$ s). The nanostructured Ni coating (purity 99.99%, $T_{\text{melt}} = 1453$ °C) was deposited by electron beam evaporation ($T = 80$ °C, residual gas pressure was $10^{-4}$ Pa, deposition rate $v = 1–2$ nm/s). The film thickness during the deposition was monitored with a quartz balance technique. The temperature of the support during deposition was controlled with a precision of ±0.5 °C. After thin film deposition Ni-PET structures were thermally annealed at 140 °C (below PET glassing temperature) for 30 minutes. It was found from XRD spectra analysis that the prepared nanostructured Ni films before and after annealing were amorphous. Atomic force microscope (AFM) study of the film surfaces showed that the size of nanostructures increased with film thickness. The average thickness of the Ni films was 10, 15, and 20 nm with corresponding resistance of square area 54, 48, and 25 $\Omega$. 

---

Fig. 1. Geometry of the rectangular shape antenna fastened to an end of a transmission line.

Fig. 2. Schematic diagram of the experimental set-up. 1 is nanosecond pulse generator, 2 coaxial supply line, 3 rectangular antenna, 4 receiving horn antenna, 5 delay line, 6 synchronization, 7 sampling oscilloscope.
3. Experimental technique

Schematic diagram of the experimental set-up is shown in Fig. 2. A mercury-wetted relay generator was used as a subnanosecond rise time pulse generator (1). The amplitude of the pulses was controlled by power supply. The 2.5×2 cm² rectangular antenna (3) was fastened at the end of a coaxial supply line (2) connected to the generator output. Signal radiated by the antenna (3) was received by horn antenna (4) and transmitted to broadband oscilloscope (7) through delay line (5). Taking into account that the oscilloscope channel bandwidth was about 0–5 GHz at the level of 3 dB (65 ps transient response) the rise time of the pulses at the end of the line (2) was chosen to be about 500 ps. Two receiving pyramidal horn antennas were used in the experiment: one having 1–18 GHz bandwidth (horn aperture 34×26 cm², length 85 cm) and another of 2–5.6 GHz bandwidth (horn aperture 12×9 cm², length 30 cm), with outputs to coaxial 50 Ω cable. The distance between the antenna (3) and the centre of the horn aperture was 80 and 30 cm, respectively.

4. Visualized signal wave forms

The signals were received by the horn antennas in the directions corresponding to x, y, z axes. It was found that signals obtained in z axis have smaller amplitude (compared to those obtained in x and y axes). Signals obtained in x and y directions had similar envelope forms and amplitudes with z axis parallel to broader side of the receiving horn aperture. The signal with the largest amplitude was obtained in x and y directions, when z axis was parallel to narrower side of the receiving aperture. It should be noted that in this case signals obtained in x and y directions slightly differed after 2–2.5 nanoseconds from the pulse beginning. Signals obtained from the Al foil antenna were similar to those obtained from Cu foil antenna, but had lower values of the amplitude. The paper and PET supports had negligible influence on electromagnetic energy absorption in the 2–5.6 GHz frequency range.

Signals of Cu and Al antennas received by the large horn in x axis are demonstrated in Fig. 3. Voltage of exciting electrical pulse from the pulse generator was 200 V. As one can see, both pulses have a quasi-Gauss envelope. Amplitude values of the signal corresponding to Al antenna are lower compared to those of Cu antenna. Similar results were obtained with resistive Ni antennas.

Signals of Cu and Ni antennas received by the large horn in y axis are shown in Fig. 4. In Ni antenna cases, one can see lower signal amplitude values and changes in signal envelope form, compared to the Cu case.

Figure 5 demonstrates signals received by the small horn in z axis direction. The exciting electrical pulse voltage from the pulse generator was 270 V. The signal consists of two wave packets (Cu antenna case). This envelope form change is due to narrower frequency band of the small horn. It is seen that the Al and Ni antennas suppress the amplitude values of the second wave packet. It also should be noted that some changes in signal form appear with increase of the exciting pulse voltage.
Fig. 5. Oscillograms received in $z$ axis by the small horn. Solid line corresponds to Cu, dashed to crumpled Al, and dash-dotted to Ni (15 nm thick) antennas. Deflection factor is 0.1 V/div., sweep range is 0.5 ns/div.

5. Discussion of results

The signals shown in Fig. 5 have spectrum range defined by the small horn. Application of equation (1) to these signals reveals that $\eta = 0.476$, therefore even the signals with changed envelope form are characterized as UWB. Figure 3 demonstrates the signals received by the large horn. The values of $f_{up}$ for these signals are unclear and are close to the set-up wideband upper frequency. In the case of quasi-Gauss pulses the difference $f_{up} - f_{low}$ can be estimated as $2/\tau$, where $\tau$ is the pulse length at the base; then $\eta = (f_{up} - f_{low})/f_0$, where $f_0$ is the mean basic frequency [3]. On the basis of Fig. 3 and Eq. (1) one can obtain that $\eta = 0.333$ (taking $\tau \approx 5$ ns, $f_0 \approx 1.2$ GHz for Cu antenna). The index $\eta$ value denotes UWB signal. In Fig. 4 we can see that the signals received in $y$ axis are shorter than those in $x$ axis (see Fig. 3) and, therefore, they should be characterized as UWB signals as well.

An attempt to use metallic coaxial cone horn of wider band ($f_{low} \approx 0$) was unsuccessful because of strong signal distortion due to internal reflections. For undistorted reception of UWB signals, TEM horns with two conducting plates having resistive coating are used. Resistive coating reduces the reflections and improves matching with 50 $\Omega$ output. Use of the horn antennas is inconvenient because of their large dimensions. Our experiments show that UWB radiation of the Al and Ni antennas is sensitive to their surface resistivity. Suppression of the amplitude values of the second wave packet by the resistive antennas (see Fig. 5) indicates a possibility to use them for radiated signal shortening. Therefore, the resistive properties of thin metal films allow one to use these materials in designing plane UWB antennas. On the other hand, the radiation can be applied to control parameters of various resistive coatings, including nanostructured films, during a deposition process. Further, if resistive properties of nanostructured coatings can be changed by external electric or magnetic fields or by optical radiation, then these coatings can be used in UWB antennas for modulation of the radiated pulses.

In our experiments the radiation is induced under conditions corresponding to the dipole radiation: linear dimension of an antenna should be smaller than the shortest wavelength in the signal spectrum [8]. Since the antennas are not matched with a cable and radiate mainly during the pulse front, the radiation is not effective enough. The estimated power radiated in all directions by the Cu antenna (oscilloscope input was 50 $\Omega$) was of about 1 W, while the exciting pulse power was 800 W. The origins of quasi-Gauss envelope form of the signal are not completely clear. Obviously, the broadening of antenna’s bandwidth and improvement of matching would result in increase of the radiated signal power with certain decrease of oscillation number of the UWB signal. The attempts to widen the set-up frequency band are continuing.

In order to increase the amplitude of the radiated pulses for long distance applications, it is necessary to use high power exciting pulses or to form high amplitude signals by using an antenna array. It is known that high power electrical pulses of nanosecond duration induce irreversible damage in films fabricated of non-metallic resistive materials [9].

AFM analysis of the annealed 20 nm thick Ni films revealed existence of nanosized semi-spheres standing out 10 nm above the surface. Due to nanosized structure, the Ni films could have certain features permitting them to withstand high power pulse action. Parameters of nanoscale films and nanoparticles such as melting temperature and heat conductivity are lower than those of corresponding bulk material. And vice versa, thermal expansion coefficient and heat capacity may be larger [10]. Nanoscale object heat emission is not investigated enough. Parameter $\alpha$ characterizing the heat transfer may be estimated from Newton’s equation $dQ/dt = \alpha \Delta T$, where $\Delta T$ is temperature difference between a heated body and ambient air or liquid. It is known that $\alpha$ can reach extremely large values when dimensions of an object are comparable with submicron thickness of an interfacial air or liquid layer in the case when heat is transferred by means of heat conductivity [11]. Metallic nanostructured films formed by a controlled size-selective synthesis could be potentially perfect heat emitting materials. Therefore, they can be
used as resistive elements in UWB antennas excited by power electrical pulses. Thus, further experimental studies are needed to fabricate metallic nanostructured thin films suitable to withstand possible damages induced by high power electrical pulses of nanosecond duration.

6. Conclusions

Our investigations show the generation of UWB electromagnetic radiation in frequency range from 1 to 5.6 GHz under excitation of plane rectangular antennas, including those with resistive coatings, by fast rising electrical pulses. Radiated pulses have a quasi-Gauss envelope form. The power of the radiated signal is lower by two orders than that of the electrical pulse.

Both the amplitude and the envelope form of the UWB pulse are sensitive to the resistive properties of the antenna coatings, and therefore:

- it is possible to use the radiation to control parameters of various resistive coatings, including nanostructured films during their fabrication;
- materials with resistive nanostructured coatings can be used to create plane compact UWB antennas;
- UWB antennas, which have resistive nanostructured coatings with properties that can be changed by external electric or magnetic fields or by optical radiation, can be used for modulation of radiated pulses.

References

Santrauka
Superplaciajuosčių elektromagnetinių impulsų generavimui panaudotos stačiakampės antenos \((2.5 \times 2 \text{ cm}^2)\), patalpintos perdirbimo linijos gale, įžadinant jas 0,5 ns augimo laiko trukmės elektriniai impulsais. Išspinduliuoti impulsai buvo priimami plačiajuosčių ruporinėmis antenomis ir atvaizduojami plačiajuosčio stroboskopinio oscilografo ekrane. Šitie impulsai buvo registruojami 1–5,6 GHz dažnių juostoje ir turėjo kvazi-Gauso gaubiamąją. Spinduliavimui buvo panaudotos Cu, Al ir nanostruktūrinės Ni stačiakampės antenos. Skirtingo storio Ni sluoksniai buvo užgirinti ant 100 µm storio polietilenos tereftalato plokščių.

Parodyta, kad superplaciajuosčius impulsus galima panaudoti elektrinėms plonų sluoksnių savybėms kontroliuoti jų garinimo proceso metu, o metalinius nanostruktūrinus sluoksnius pritaikyti kuriant superplaciajuosčių perdavimo ir priėmimo antenas su pavarinių rezistyniais elementais. Tokias antenas su nanostruktūrinėmis dangomis, jautriomis išorinio elektrinio arba magnetinio lauko arba optinės spinduliavimosios poveikiai, galima panaudoti plačiajuosčio spinduliavimo moduliavimui. Pasiūlyta ištirti galiomąją nanostruktūrinės metalinių sluoksnių fizikines savybes, kad jie nebūtų ardomi sužadinant galingais trumpais elektriniai impulsais.